PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant(s):

MUKAIHARA, T. et al.

Serial No.:

09/513,702

Filed:

February 25, 2000

For:

SEMICONDUCTOR

LASER DEVICE

Group Art Unit:

Examiner:

2877

Delma R. Flores-Ruiz

Attorney Docket:

00120/HG (007742-0034)

[6635-60672]

HAND DELIVERED BY COURIER ON OR BEFORE 12/17/02

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SUPPLEMENTAL INFORMATION DISCLOSURE STATEMENT PURSUANT TO 37 C.F.R. §1.56 AND §§1.97-1.98

Commissioner for Patents Washington, D.C. 20231

Sir:

The citation(s) listed on the enclosed PTO-1449 Form is (are) submitted under 37 C.F.R. §§1.97 and 1.98, and in compliance with the duty of disclosure as defined in 37 C.F.R. §1.56. The Examiner is requested to make this(these) citation(s) officially of record in the application. This Information Disclosure Statement is being submitted after the mailing of the first Office Action for the above-identified application and, to the knowledge of the undersigned, before the mailing of either a final action or a notice of allowance. Accordingly, it is believed by the undersigned that a petition and petition fee under 37 C.F.R. §1.97(d) are not required.

Certification under 37 C.F.R. §1.97(d) and (e).

Pursuant to 37 C.F.R. §1.97(e)(2), the undersigned, Hal R. Yeager, hereby certifies that no item of information contained in this Information Disclosure Statement was cited in a communication from a foreign patent office in a counterpart foreign application and, to the

SUPPLEMENTAL INFORMATION DISCLOSURE STATEMENT Serial No. 09/513,702 (007742-34) Page 2

knowledge of the undersigned after making reasonable inquiry, no item of information contained in this Information Disclosure Statement was known to any individual designated in 37 C.F.R. §1.56(c) more than three months prior to the filing of this Statement.

Each item of information contained in this Information Disclosure Statement was cited in a communication from a foreign patent office in a **non**-counterpart foreign application not more than three months prior to the filing of this statement.

This Information Disclosure Statement Under 37 C.F.R. §1.56 is not to be construed as a representation that any of the listed citations establishes, by itself or in combination with other information, a *prima facie* case of unpatentability of any claim in the above-identified application. Additionally, this Information Disclosure Statement is not to be construed as a representation that a further search of the art has been made by Applicants, or that additional information relevant to the examination of this application does not exist unbeknownst to Applicants.

Respectfully submitted,

Hal R. Yeager

Registration No. 35,419

December 14, 2002 COUDERT BROTHERS, LLP 600 Beach Street, 3RD Floor San Francisco, CA 94109 Telephone: (415) 409-2900

Telefax: (415) 409-7400

FORM PTO-1449 (Modified)



LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT(S)' INFORMATION DISCLOSURE STATEMENT

(Use several sheets if necessary)

ATTY. DOCKET NO. 00120/HG (07742-34) SERIAL NO.

09/513,702

APPLICANT Toshikazu MUKAIHARA, et al.

FILING DATE:

February 25, 2000

GROUP ART UNIT: 2877

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U.S. PATENT DOCUMENTS

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| EXAM'R INITIAL | | DOCUMENT NUMBER | DATE | NAME | Class | Subclass | Filing Date If Appropriate |
| DWW | A1 | 5,189,679 | 02/23/1993 | Derry, Jr. | 372 | 45 | |
| DWIL | A2 | 5,737,474 | 04/07/1998 | Aoki, et al. | 385 | 131 | |
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| INITIAL | | NUMBER | | | | | yes | no |
| | B1 | | | | | | | |
| | B2 | | | | | | | |

OTHER ART (Include Author, Title, Date, Pertinent Pages, Etc.)

| Dug | C1 | T. Kamijoh, <i>et. al.</i> , "Improved Operation Characteristics of Long-Wavelength Lasers Using Strained MQW Active Layers," IEEE Journal of Quantum Electronics, Vol. 30, No. 2, pages 524-532, February 1994, IEEE, New York. |
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| | C3 | |

| EXAMINER | Delma | R. Flrs | Ruin | |
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EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to Applicant(s).